VS-30CTQ050-M3, VS-30CTQ060-M3

**Vishay Semiconductors** 

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PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> 2 x 15 A					
V <sub>R</sub>	50 V, 60 V				
V <sub>F</sub> at I <sub>F</sub>	0.56 V				
I <sub>RM</sub> typ.	45 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
E <sub>AS</sub>	13 mJ				
Package	TO-220AB 3L				
Circuit configuration	Common cathode				

### **FEATURES**

• High

- 150 °C T<sub>J</sub> operation
- · Very low forward voltage drop
- High frequency operation



COMPLIANT

- HALOGEN purity, high temperature epoxy FREE encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL CHARACTERISTICS VALUES UN						
I <sub>F(AV)</sub>	Rectangular waveform	30	А			
V <sub>RRM</sub>		50/60	V			
IFSM	t <sub>p</sub> = 5 μs sine	1000	Α			
V <sub>F</sub>	15 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.56	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-30CTQ050-M3 VS-30CTQ060-M3 UNITS						
Maximum DC reverse voltage	V <sub>R</sub>	50	60	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	50	00	v		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS		UNITS		
Maximum average forward per devic		50 % duty cycle at $T_{-} = 105$ °C	rootongular wayoform	30			
current, see fig. 5 per le	I <sub>F(AV)</sub>	50 % duty cycle at $T_C = 105$ °C, rectangular waveform		15			
Maximum peak one cycle non-repetitive		5 $\mu$ s sine or 3 $\mu$ s rect. pulse	Following any rated load	1000	A		
surge current per leg, see fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	260			
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.50 A, L = 11.5 mH		13	mJ		
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by $T_J$ maxim		1.50	А		

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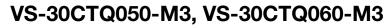
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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS			
		15 A	T.I = 25 °C	0.62			
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	30 A	1j=25 C	0.82	v		
See fig. 1	VFM ()	15 A	T <sub>.1</sub> = 125 °C	0.56			
		30 A	1j = 125 0	0.71			
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.80	mA		
Maximum reverse leakage current per leg		T <sub>J</sub> = 125 °C	VR - naleu VR	160			
Typical reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	45	mA		
Threshold voltage	V <sub>F(TO)</sub>			0.39	V		
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$		8.47	mΩ		
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal ran	720	pF			
Typical series inductance per leg	Ls	Measured lead to lead 5 m	nm from package body	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs		

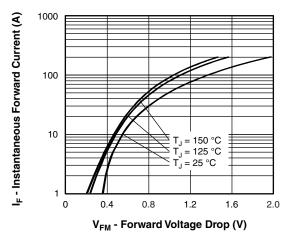
#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storag temperature range	е	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C			
Maximum thermal resistance, junction to case per leg		P	DC operation	3.25				
Maximum thermal resistance, junction to case per package		R <sub>thJC</sub>	DC operation	1.63	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf ⋅ in)			
Marking davias			Case style TO 220AD 21	30CT	Q050			
Marking device			Case style TO-220AB 3L	30CTQ060				



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Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

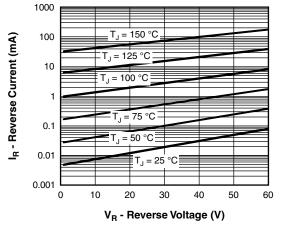


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

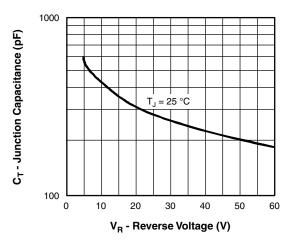


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

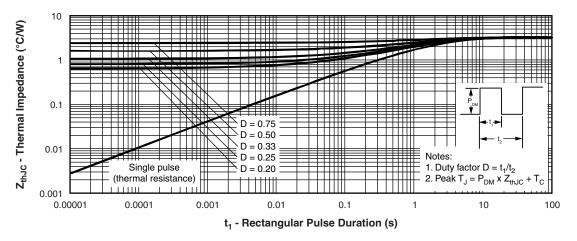
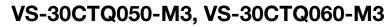


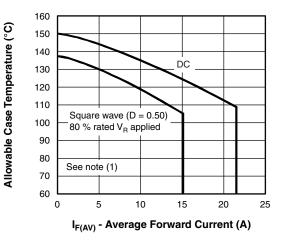
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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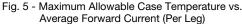
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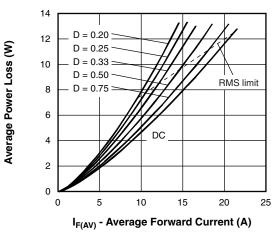


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

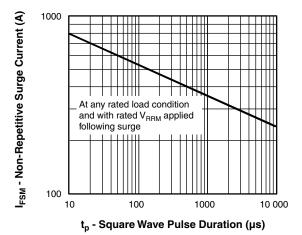


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

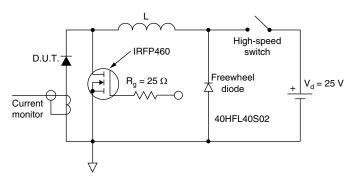


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

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## VS-30CTQ050-M3, VS-30CTQ060-M3



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### **ORDERING INFORMATION TABLE**

Device code	VS-	30	с	т	Q	060	-МЗ
		2	3	4	5	6	7
		- Visl	nay Sen	niconduc	ctors pro	oduct	
	2 -			ng (30 = iguratior	,		
		C =	commo	n cathoo			
	4		kage: TO-220	I			
	5		-	" series		ſ	050 = 5
	6 ·		age rati	-			060 = 6
	7			ntal digit gen-free,		complia	ont and

ORDERING INFORMATION (Example)					
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION					
VS-30CTQ050-M3	50	Antistatic plastic tubes			
VS-30CTQ060-M3	50	Antistatic plastic tubes			

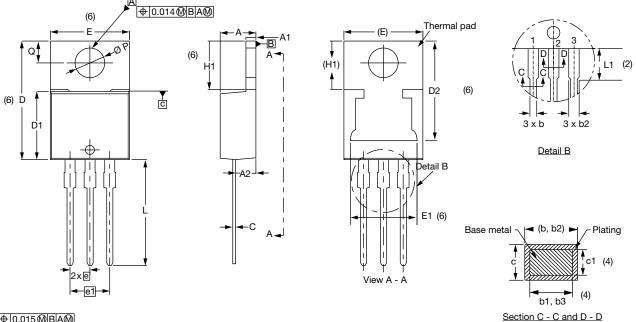
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96154				
Part marking information	www.vishay.com/doc?95028			



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## **TO-220AB 3L**

### **DIMENSIONS** in millimeters and inches



#### ⊕0.015@BA@



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SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	I WILLINETERS			INCHES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	11.68	13.30	0.460	0.524	6, 7	
E	10.11	10.51	0.398	0.414	3, 6	
E1	6.86	8.89	0.270	0.350	6	
е	2.41	2.67	0.095	0.105		
e1	4.88	5.28	0.192	0.208		
H1	6.09	6.48	0.240	0.255	6	
L	13.52	14.02	0.532	0.552		
L1	3.32	3.82	0.131	0.150	2	
ØP	3.54	3.91	0.139	0.154		
Q	2.60	3.00	0.102	0.118		

INCHES

#### Notes

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

<sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only

<sup>(5)</sup> Controlling dimensions: inches

- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

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Conforms to JEDEC<sup>®</sup> outline TO-220AB

MILLIMETEDS

 $<sup>^{(1)}\,</sup>$  Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>&</sup>lt;sup>(3)</sup> Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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